

GA100JT12-227

GA100JT12-227 Information

www.newner.com	 GA100JT12-227 GeneSiC Semiconductor Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single TRANS SJT 1200V 160A SOT227 SOT-227-4, miniBLOC For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GA100JT12-227 Specifications

Manufacturer Part Number	GA100JT12-227	
Manufacturer	GeneSiC Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Single	
Package	SOT-227-4, miniBLOC	
Series	-	
FET Type	-	
Technology	SiC (Silicon Carbide Junction Transistor)	
Drain to Source Voltage (Vdss)	1200V	
Current - Continuous Drain (Id) @ 25°C	160A	
Drive Voltage (Max Rds On, Min Rds On)	-	
Vgs(th) (Max) @ Id	-	
Gate Charge (Qg) (Max) @ Vgs	-	
Input Capacitance (Ciss) (Max) @ Vds	14400pF @ 800V	
Vgs (Max)	-	
FET Feature	-	
Power Dissipation (Max)	535W (Tc)	
Rds On (Max) @ Id, Vgs	10 mOhm @ 100A	
Operating Temperature	-55°C ~ 175°C (TJ)	
Mounting Type	Chassis Mount	
Supplier Device Package	SOT-227	
Package / Case	SOT-227-4, miniBLOC	
	Report errors?	

GA100JT12-227 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GA100JT12-227 Payment Methods



GA100JT12-227 Shipping Methods



If you have any question about GA100JT12-227, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com